HALOGEN

FREE GREEN



Vishay Semiconductors

High Speed Infrared Emitting Diode, 890 nm, Surface Emitter Technology



FEATURES

Package type: leadedPackage form: T-1¾

• Dimensions (in mm): Ø 5

· Leads with stand-off

• Peak wavelength: $\lambda_p = 890 \text{ nm}$

· High reliability

• High radiant power

• High radiant intensity

• Angle of half intensity: $\varphi = \pm 10^{\circ}$

· Low forward voltage

· Good spectral matching to Si photodetectors

 Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>



TSHF5211 is an infrared, 890 nm emitting diode in surface emitter chip technology with high radiant power and high speed, molded in a clear, untinted plastic package.

APPLICATIONS

Industrial sensors

PRODUCT SUMMARY					
COMPONENT	I _e (mW/sr)	φ (°)	$\lambda_{\mathbf{p}}$ (nm)	t _r (ns)	
TSHF5211	235	± 10	890	15	

Note

Test conditions see table "Basic Characteristics"

ORDERING INFORMATION						
ORDERING CODE	PACKAGING REMARKS		PACKAGE FORM			
TSHF5211	Bulk	MOQ: 4000 pcs, 1000 pcs/reel	T-1¾			
TSHF5211-MS21	Tape and reel	MOQ: 5000 pcs, 1000 pcs/reel	T-1¾			
TSHF5211-MSZ	Ammopack	MOQ: 5000 pcs, 1000 pcs/reel	T-1¾			

Note

MOQ: minimum order quantity

ABSOLUTE MAXIMUM RATINGS (T _{amb} = 25 °C, unless otherwise specified)					
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT	
Forward current		I _F	100	mA	
Peak forward current	$t_p/T = 0.5$, $t_p = 100 \mu s$	I _{FM}	200	mA	
Surge forward current	t _p = 100 μs	I _{FSM}	1.0	А	
Power dissipation		P _V	170	mW	
Junction temperature		Tj	100	°C	
Ambient temperature range		T _{amb}	-40 to +85	°C	
Storage temperature range		T _{stg}	-40 to +100	°C	
Soldering temperature	t ≤ 5 s, 2 mm from case	T _{sd}	260	°C	
Thermal resistance junction to ambient (1)	EIA / JESD51	R _{thJA}	230	K/W	

Note

(1) The emitted optical signal was not considered



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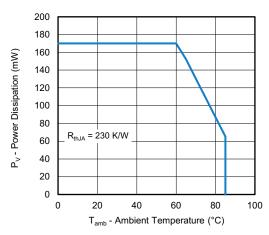


Fig. 1 - Power Dissipation vs. Ambient Temperature

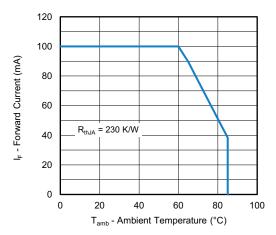


Fig. 2 - Forward Current vs. Ambient Temperature

BASIC CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Forward voltage	$I_F = 100 \text{ mA}, t_p = 20 \text{ ms}$	V _F	-	1.5	1.7	V
	$I_F = 1 \text{ A}, t_p = 100 \mu \text{s}$	V _F	-	2.5	-	V
Temperature coefficient of V _F	I _F = 1 mA	TK _{VF}	-	-1.0	-	mV/K
Reverse current		I _R	Not designed for reverse operation			
Junction capacitance	V _R = 0 V, f = 1 MHz, E = 0	C _j	-	45	-	pF
Radiant intensity	$I_F = 100 \text{ mA}, t_p = 20 \text{ ms}$	l _e	150	235	340	mW/sr
	$I_F = 1 \text{ A}, t_p = 100 \mu \text{s}$	l _e	-	1800	-	mW/sr
Radiant power	$I_F = 100 \text{ mA}, t_p = 20 \text{ ms}$	φ _e	-	50	-	mW
Temperature coefficient of ϕ_e	I _F = 100 mA	TKφe	-	-0.2	-	%/K
Angle of half intensity		φ	-	± 10	-	0
Peak wavelength	I _F = 100 mA	λ_{p}	-	890	-	nm
Spectral bandwidth	I _F = 100 mA	Δλ	-	40	-	nm
Temperature coefficient of λ_p	I _F = 100 mA	TKλ _p	-	0.3	-	nm/K
Rise time	I _F = 100 mA	t _r	-	15	-	ns
Fall time	I _F = 100 mA	t _f	-	15	-	ns

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BASIC CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)

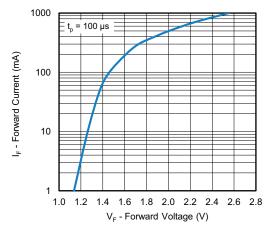


Fig. 3 - Forward Current vs. Forward Voltage

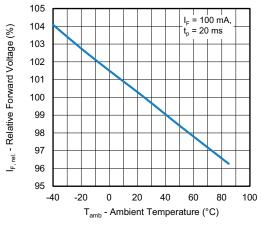


Fig. 4 - Forward Voltage vs. Ambient Temperature

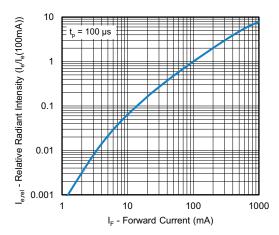


Fig. 5 - Relative Radiant Intensity vs. Forward Current

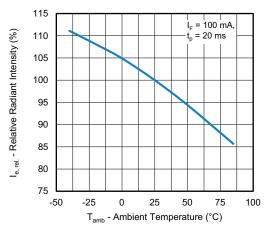


Fig. 6 - Relative Radiant Intensity vs. Ambient Temperature

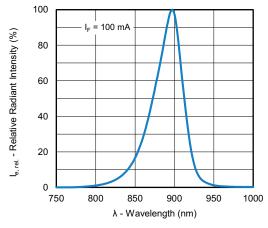


Fig. 7 - Relative Radiant Intensity vs. Wavelength

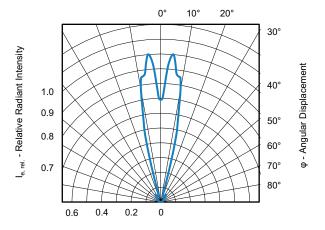


Fig. 8 - Relative Radiant Intensity vs. Angular Displacement



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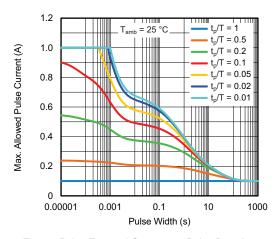


Fig. 9 - Pulse Forward Current vs. Pulse Duration at 25 °C

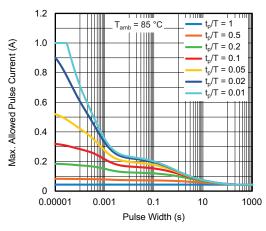
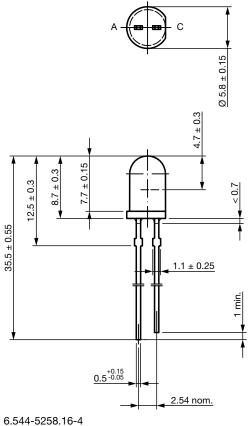
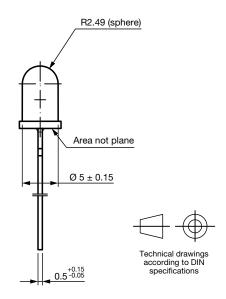


Fig. 10 - Pulse Forward Current vs. Pulse Duration at 85 °C

PACKAGE DIMENSIONS in millimeters



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